2N5551ZL1

2N5551ZL1 Information

For Reference Only

Part Number 2N5551ZL1
Manufacturer ON Semiconductor
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single
Description TRANS NPN 160V 0.6A TO-92
Package TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

2N5551ZL1 Specifications

Manufacturer Part Number	2N5551ZL1
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	600mA
Voltage - Collector Emitter Breakdown (Max)	160V
Vce Saturation (Max) @ Ib, Ic	200mV @ 5mA, 50mA
Current - Collector Cutoff (Max)	50nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Power - Max	625mW
Frequency - Transition	300MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Supplier Device Package	TO-92-3
	Report errors?

2N5551ZL1 Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

2N5551ZL1 Payment Methods

2N5551ZL1 Shipping Methods

If you have any question about 2N5551ZL1, please do not hesitate to contact us!
Website: https://www.heisener.com
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